TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC7MB3251FT, TC7MB3251FK

### 1-of-8 FET Multiplexer/Demultiplexer

The TC7MB3251 is high-speed CMOS 1-8 multiplexer/demultiplexer. The low on resistance of the switch allows connections to be made with minimal propagation delay time.

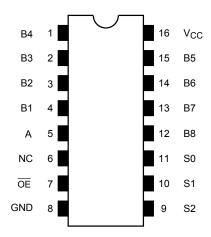
This device is 1 to 8 multiplexer/demultiplexer controlled by the combination of select inputs (S0, S1, S2) and output enable ( $\overline{\text{OE}}$ ). The A inputs is connected to the corresponded B1to B8 outputs determined by the combination both the select inputs (S0, S1, S2) and output enable ( $\overline{\text{OE}}$ ). When the output enable ( $\overline{\text{OE}}$ ) input is held "H" level, the switches are open with regardless the state of select inputs and a high-impedance state exists between the switches.

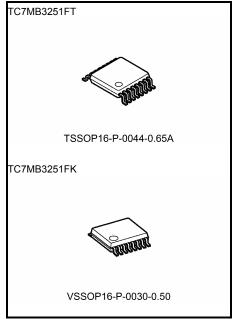
All inputs are equipped with protection circuits against static discharge.

#### **Features**

- Operating voltage: V<sub>CC</sub> = 4.5 to 5.5 V
- High speed:  $t_{pd} = 0.25 \text{ ns (max)}$
- Low on resistance:  $RON = 5 \Omega$  (typ.)
- ESD performance: Machine model  $\geq \pm 200 \text{ V}$ Human body model  $\geq \pm 2000 \text{ V}$
- Compatible with TTL outputs (control inputs)
- Package: TSSOP16,VSSOP16 (US16)
- Pin compatible with the 74xx251 type. Functionally equivalent to (FST/CBT) 3251.

### Pin Assignment (top view)





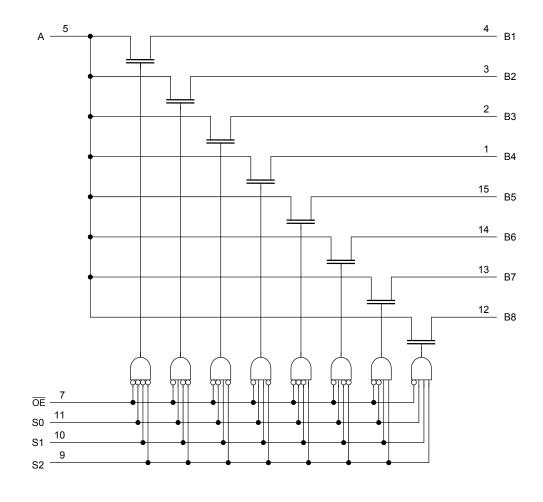
Weight:

TSSOP16-P-0044-0.65A : 0.06 g (typ.) VSSOP16-P-0030-0.50 : 0.02 g (typ.)

## **Truth Table**

	Inp	Function		
ŌĒ	S2	S1	S0	Tunction
L	L	L	L	A port = B1 port
L	L	L	Н	A port = B2 port
L	L	Н	L	A port = B3 port
L	L	Н	Н	A port = B4 port
L	Н	L	L	A port = B5 port
L	Н	L	Н	A port = B6 port
L	Н	Н	L	A port = B7 port
L	Н	Н	Н	A port = B8 port
Н	Х	Х	Х	Disconnect

## **System Diagram**





#### **Absolute Maximum Ratings (Note)**

Characteristics	Symbol	Rating	Unit	
Power supply range	V <sub>CC</sub>	-0.5 to 7.0	V	
DC input voltage	V <sub>IN</sub>	-0.5 to 7.0	٧	
DC switch voltage	VS	−0.5 to 7.0	٧	
Input diode current	I <sub>IK</sub>	-50	mA	
Continuous channel current	IS	128	mA	
Power dissipation	P <sub>D</sub>	180	mW	
DC V <sub>CC</sub> /GND current	I <sub>CC</sub> /I <sub>GND</sub>	±100	mA	
Storage temperature	T <sub>stg</sub>	-65 to 150	°C	

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

### **Operating Ranges (Note)**

Characteristics	Symbol	Rating	Unit	
Supply voltage	Vcc	4.5 to 5.5	V	
Input voltage ( $\overline{\sf OE}$ , S)	V <sub>IN</sub>	0 to 5.5	V	
Switch voltage	Vs	0 to 5.5	V	
Operating temperature	T <sub>opr</sub> -40 to 85		°C	
Input rise and fall time	dt/dv	0 to 10	ns/V	

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either  $V_{CC}$  or GND.



#### **Electrical Characteristics**

#### DC Characteristics ( $Ta = -40 \text{ to } 85^{\circ}\text{C}$ )

Characteristics		Symbol	Test Condition V <sub>CC</sub> (V)		Min	Typ. (Note 1)	Max	Unit	
Innut valtage	"H" level	V <sub>IH</sub>	_		4.5 to 5.5	2.0	_	_	V
Input voltage	"L" level	V <sub>IL</sub>	_		4.5 to 5.5	_	_	0.8	V
Input leakage cur	rent ( OE , S)	I <sub>IN</sub>	V <sub>IN</sub> = 0 to 5.5 V		4.5 to 5.5	_	_	±1.0	μΑ
Power off leakage current		l <sub>OFF</sub>	A, B, $\overline{OE} = 0 \text{ to } 5.5 \text{ V}$		0	_	_	±1.0	μΑ
Off-state leakage current (switch off)		I <sub>SZ</sub>	A, B = 0 to 5.5 V, $\overline{OE} = V_{CC}$		4.5 to 5.5	_	_	±1.0	μА
ON resistance (Note 2)		R <sub>ON</sub>	V <sub>IS</sub> = 0 V	$I_{IS} = 64 \text{ mA}$	4.5	_	5	7	
				I <sub>IS</sub> = 30 mA	4.5	_	5	7	Ω
			V <sub>IS</sub> = 2.4 V, I <sub>IS</sub> = 15 mA		4.5	_	10	15	
Quiescent supply current		Icc	$V_{IN} = V_{CC}$ or GND, $I_{OUT} = 0$ 5.		5.5	_	_	10	μА
Increase in I <sub>CC</sub> per input		Δlcc	V <sub>IN</sub> = 3.4 V (one input)		5.5	_	_	2.5	mA

Note 1: Typical values are at  $V_{CC} = 5 \text{ V}$ ,  $Ta = 25^{\circ}\text{C}$ .

Note 2: Measured by the voltage drop between A and B pins at the indicated current through the switch. ON resistance is determined by the lower of the voltages on the two (A or B) pins.

#### AC Characteristics ( $Ta = -40 \text{ to } 85^{\circ}\text{C}$ )

Characteristics	Symbol	Test Condition		Min	Max	Unit
Characteristics	Test Condition		V <sub>CC</sub> (V)	IVIIII	IVIAX	Offic
Propagation delay time	t <sub>pLH</sub>	Figure 1, Figure 2 (Note)	4.5		0.25	ns
(bus to bus)	t <sub>pHL</sub>	rigure 1, rigure 2 (Note)	7.5		0.20	2
Propagation delay time	t <sub>pLH</sub>	Figure 1, Figure 2	4.5		6.0	
(S to bus)	t <sub>pHL</sub>	rigure 1, rigure 2	4.5		0.0	ns
Output enable time	t <sub>pZL</sub>	Figure 4 Figure 2	4.5		5.6	
( OE to bus)	t <sub>pZH</sub>	Figure 1, Figure 3	4.5		5.0	ns
Output enable time	t <sub>pZL</sub>	Figure 1 Figure 2	4.5		5.6	no
(S to bus)	t <sub>pZH</sub>	Figure 1, Figure 3	4.5		5.0	ns
Output disable time	t <sub>pLZ</sub>	Figure 4 Figure 2	4.5		0.4	
( OE to bus)	t <sub>pHZ</sub>	Figure 1, Figure 3	4.5		6.4	ns
Output disable time	t <sub>pLZ</sub>	Figure 4 Figure 2	4.5		6.4	
(S to bus)	t <sub>pHZ</sub>	Figure 1, Figure 3	4.5	_	6.4	ns

Note: This parameter is guaranteed by design but is not tested. The bus switch contributes no propagation delay other than the RC delay of the typical on resistance of the switch and the 50 pF load capacitance, when driven by an ideal voltage the source (zero output impedance).

### **Capacitive Characteristics (Ta = 25°C)**

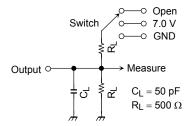
Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Тур.	Unit
Control pin input capacitance ( $\overline{\text{OE}}$ , S)	CIN	(Note)	5.0	3	pF
Switch terminal capacitance (B)	C <sub>I/O</sub>	$\overline{OE} = V_{CC}$ (Note)	5.0	10	pF
Switch terminal capacitance (A)	C <sub>I/O</sub>	$\overline{OE} = V_{CC}$ (Note)	5.0	59	pF

4

Note: This parameter is guaranteed by design.



#### **AC Test Circuit**



Parameter	Switch		
t <sub>pLH</sub> , t <sub>pHL</sub>	Open		
t <sub>pLZ</sub> , t <sub>pZL</sub>	7.0 V		
t <sub>pHZ</sub> , t <sub>pZH</sub>	Open		

Figure 1

#### **AC Waveform**

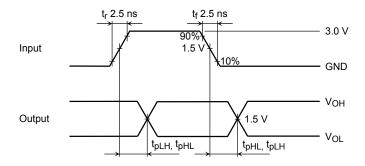


Figure 2 t<sub>pLH</sub>, t<sub>pHL</sub>

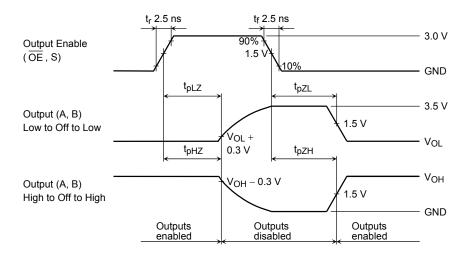
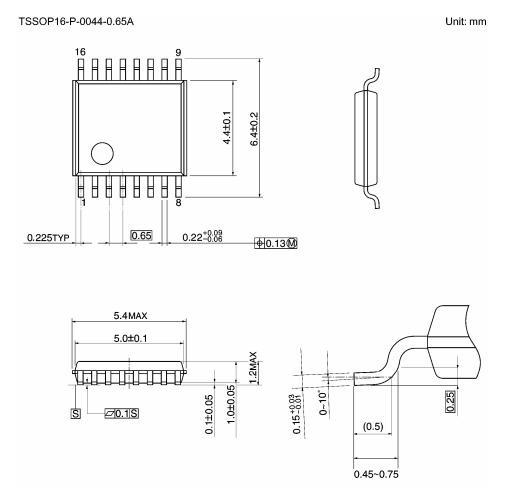


Figure 3  $t_{pLZ}$ ,  $t_{pHZ}$ ,  $t_{pZL}$ ,  $t_{pZH}$ 

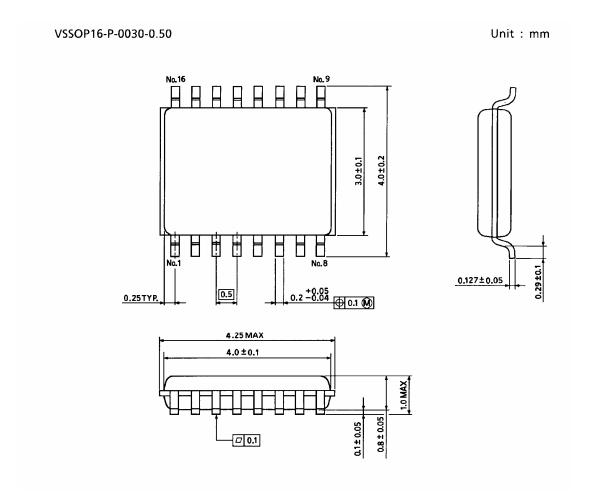
5 2008-09-01

## **Package Dimensions**



Weight: 0.06 g (typ.)

### **Package Dimensions**



Weight: 0.02 g (typ.)

#### RESTRICTIONS ON PRODUCT USE

20070701-EN GENERAL

- The information contained herein is subject to change without notice.
- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property.
  In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc.
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in his document shall be made at the customer's own risk.
- The products described in this document shall not be used or embedded to any downstream products of which
  manufacture, use and/or sale are prohibited under any applicable laws and regulations.
- The information contained herein is presented only as a guide for the applications of our products. No
  responsibility is assumed by TOSHIBA for any infringements of patents or other rights of the third parties which
  may result from its use. No license is granted by implication or otherwise under any patents or other rights of
  TOSHIBA or the third parties.
- Please contact your sales representative for product-by-product details in this document regarding RoHS
  compatibility. Please use these products in this document in compliance with all applicable laws and regulations
  that regulate the inclusion or use of controlled substances. Toshiba assumes no liability for damage or losses
  occurring as a result of noncompliance with applicable laws and regulations.

3 2008-09-01